Cyclopentanone Ethyl Lactate

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Table 2. Suggested Line Solvents

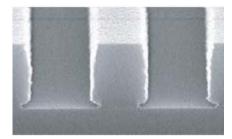


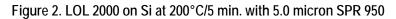
MICROPOSIT™ LOL™ 1000 AND 2000 LIFTOFF LAYERS

For Microlithography Applications

Regional Product Availability	 North America Europe, Middle East and Africa Latin America Asia-Pacific
Description	MICROPOSIT LOL 1000/2000 Liftoff Layer is an enhanced dissolution rate, dyed PMGI (polymethylglutarimide) solution used for lift-off processes requiring tight CD control, such as GMR thin film head, gallium arsenide, and other leading-edge semiconductor applications. The LOL bilayer lift-off process is suitable for applications where a thin layer of metal is sputtered or evaporated in an additive process. CD variation due to etch bias inherent in subtractive processes is eliminated, resulting in superior metal line width control. Attack on the substrate by an etchant is eliminated.
Advantages	 Submicron lift-off capability Dissolution rate optimized for controlled undercut Excellent adhesion to thin film head and semiconductor substrates Developed to work with DUV, and 193 nm photoresists Compatible with g-, h-, and i-Line and 193 nm photoresists Compatible with TMAH and metal-ion-containing developers Residue-free removal using standard MICROPOSIT Remover 1165 Simplified process—no DUV flood exposure, silylation or chlorobenzene required Excellent batch-to-batch consistency

Figure 1. LOL 1000 on Si at 200°C/5 min. with 0.5 micron SPR™ 950







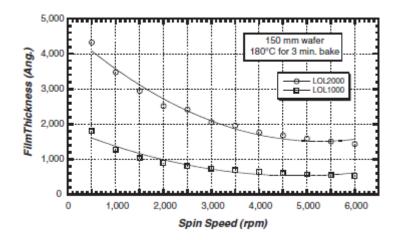
Substrate Preparation

LOL lift-off layers provide excellent adhesion over a variety of substrates, including titanium, nickel-iron, tantalum, copper, silicon and silicon nitride. Surfaces should be clean and dry before application of LOL. If increased adhesion is required, a dehydration bake of 125°C for 30–60 minutes can be used. Use of an HMDS prime is not required for most substrates. For silicon, the optimum contact angle for maximum adhesion is 35°.

Coat (LOL) LOL provides uniform defect-free coating over a thickness range of 500–1,200Å. The film thickness versus spin speed plot displayed in *Figure 3* provides the information required to meet process-dependent thickness specifications. For optimal lift-off, an LOL film thickness greater than the sputtered metal coating thickness is recommended.

LOL can be dispensed with low viscosity resist pumping systems (1–3 cSt) or nitrogen pressure dispense systems. Pumping and coating systems should be compatible with cyclopentanone. A dedicated spin bowl and drain should be used for LOL products. When photoresist is mixed with LOL, a very viscous film is formed that can cause the drain line to clog.

Figure 3. Spin Speed vs. Thickness



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Edge Bead Removal (LOL)

MICROPOSIT EC Solvent 11 is recommended for removing LOL build-up occurring at the edge of the wafer during spin coating. EC Solvent 11 is free of EGMEA, as well as acetone and xylene. EC Solvent 11 can be used with coating equipment designed to include an edge bead removal process.

Cure (LOL) A key feature of LOL is the ability to optimize the desired undercut by adjusting the dissolution rate through softbake.

Figure 4 shows how bake time and temperature affect dissolution rate to control undercut profile. Either hotplate or convection ovens can be used for softbake process steps. Again, selection of optimal bake time and temperature is based on the specific application requirements for undercut and top imaging resist selection.

Figure 4. Dissolution Rate

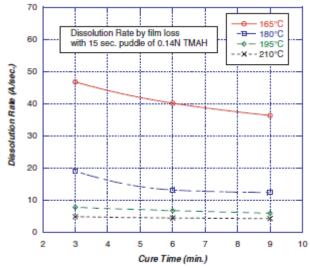


Table 3. Recommended Process Conditions	
LOL 1000 Thickness	550–1,850Â
LOL 2000 Thickness	1,850–4,250Å
LOL Cure	140–225°C/1 to 10 min.

Film Thickness Measurement (LOL)

The n and k values at 193 nm, 248 nm and 365 nm are shown in *Table 4*. Cauchy coefficients for LOL products are shown in Table 5. This information is required for measurement tools calculating film thickness. For tools not requiring Cauchy coefficients, use the refractive indices listed in *Table 4*.

Table 4. Optical Constants (all bakes for 3 min.)

	436 nm		365 nm		248 nm		193 nm	
	n	k	n	k	n	k	n	k
140°C	1.616	0.088	1.542	0.078	1.669	0.041	1.570	0.175
150°C	1.610	0.082	1.546	0.067	1.674	0.037	1.567	0.168
160°C	1.600	0.068	1.550	0.047	1.679	0.035	1.582	0.152
170°C	1.585	0.055	1.553	0.031	1.680	0.031	1.579	0.144
180°C	1.569	0.037	1.557	0.016	1.676	0.026	1.572	0.135
190°C	1.559	0.016	1.563	0.007	1.669	0.021	1.563	0.125
200°C	1.553	0.002	1.565	0.004	1.663	0.018	1.552	0.120
210°C	1.553	0.002	1.566	0.003	1.663	0.018	1.548	0.12

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	Table 5. Cauchy Coeffi	cients (all bakes for 3 min)		
	Temperature	n1	n2	n3	
	140°C	1.568	-9.7E+04	6.3E+13	
	150°C	1.566	-7.7E+05	5.7E+13	
	160°C	1.559	-5.1E+04	3.7E+13	
	170°C	1.552	1.8E+05	2.8E+13	
	180°C	1.542	3.1E+05	1.9E+13	
	190°C	1.529	5.7E+05	5.5E+12	
	200°C	1.521	5.1E+05	2.5E+12	
	210°C	1.521	5.2E+05	2.3E+12	
Expose (Image Layer) Post-Exposure Bake (Imaging	eliminating a process step in production. It is the softbake parameters that are primarily used to control the dissolution rate of LOL. However, exposure and profile of the image layer does affect level of undercut by speeding the development of the imaging resist, allowing more time for the developer solution to be in contact with the LOL layer. Although PEB is not needed for LOL, PEBs may be used for optimization of top imaging layers. See image layer data sheet for PEB recommendations.				
Layer)					
Develop	(MIB) developers. The between the top imagi	patible with both TMAH lift-off undercut is prod ng resist and the LOL for depends on individual	uced by the difference or a given developer. T	in dissolution rate he choice of optimum	
Evaporate/Sputter Metal	PVD tools. Step cover	patible with processing age achieved from a sp eposited metal pattern.			
Strip (Deposition Liftoff Step)	and excess deposited	mmended for use in str metal. For removing m ank and 30 min. for sec	etallized liftoff layers, u		

Handling Precautions	Before using this product, associated generic chemicals or the analytical reagents required for its control, consult the supplier's Material Safety Data Sheet (MSDS)/Safety Data Sheet (SDS) for details on material hazards, recommended handling precautions and product storage.
	CAUTION! Keep combustible and/or flammable products and their vapors away from heat, sparks, flames and other sources of ignition including static discharge. Processing or operating at temperatures near or above product flashpoint may pose a fire hazard. Use appropriate grounding and bonding techniques to manage static discharge hazards.
	CAUTION! Failure to maintain proper volume level when using immersion heaters can expose tank and solution to excessive heat resulting in a possible combustion hazard, particularly when plastic tanks are used.
Storage	Store products in tightly closed original containers at temperatures recommended on the product label.
Disposal Considerations	Dispose in accordance with all local, state (provincial) and federal regulations. Empty containers may contain hazardous residues. This material and its container must be disposed in a safe and legal manner.
	It is the user's responsibility to verify that treatment and disposal procedures comply with local, state (provincial) and federal regulations. Contact your Dow Electronic Materials Technical Representative for more information.
Product Stewardship	Dow has a fundamental concern for all who make, distribute, and use its products, and for the environment in which we live. This concern is the basis for our product stewardship philosophy by which we assess the safety, health, and environmental information on our products and then take appropriate steps to protect employee and public health and our environment. The success of our product stewardship program rests with each and every individual involved with Dow products - from the initial concept and research, to manufacture, use, sale, disposal, and recycle of each product.
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